

EAST Search History**EAST Search History (Prior Art)**

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S58	0	current same electrolytic near solution same energization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/16 18:24
S59	40	current same electrolytic near solution same energization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/16 18:24
S60	129	current same electrolytic near solution and energization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/16 18:26
S61	32	current same electrolytic near solution and energization and semiconduct\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/16 18:28
S62	2298	current same electrolytic near solution and semiconduct\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/16 18:30
S63	48	chemical oxidation polymerization same current	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/16 18:39
S64	23	electrolytic polymerization same semiconduct\$3 layer and pores	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/16 18:53
S65	5	"576416".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 09:06

S66	2	porous cathode and electrolytic near2 polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/17 11:34
S67	57	pores with cathode and electrolytic near2 polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2010/05/17 11:35
S68	795	dielectric near3 surface near6 cathode	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:12
S69	73	dielectric near3 surface near6 cathode and electrolytic near4 polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:12
S70	18	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:19
S71	0	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization and cathode near positive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:32
S72	7609	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization and cathode near positive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:32
S73	0	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization and cathode near positive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:32

S74	0	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization and cathode near3 positive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:32
S75	2	dielectric near3 surface near6 cathode same (pores or porosity or porous) and electrolytic near4 polymerization and cathode same positive	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 12:32
S76	449	inorganic adj semiconductor and electrolytic	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 19:00
S77	82	inorganic adj semiconductor and electrolytic near2 polymerization	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/17 19:00
S78	5	"576416".ap.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/05/20 12:39
S79	25	(US-20020191367-\$ or US-20030007318-\$ or US-20030104923-\$ or US-20030133256-\$ or US-20020039274-\$ or US-20020001168-\$ or US-20070002526-\$ or US-20030081373-\$ or US-20020001169-\$ or US-20060047030-\$). did. or (US- 6660188-\$ or US- 6343005-\$ or US- 4943892-\$ or US- 6088218-\$ or US- 6671168-\$ or US- 6361572-\$ or US- 6515848-\$ or US- 7169509-\$ or US- 6696138-\$ or US- 6580601-\$ or US- 6413282-\$). did. or (WO-02092864-\$ or WO-2005031772-\$ or JP-2003272954-\$ or JP-2001102257-\$). did.	US-PGPUB; USPAT; DERWENT	OR	ON	2010/05/20 14:17

S80	16	impregnat\$5 and S79	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 14:17
S81	174	inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 15:00
S82	5	"576416".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 15:47
S83	5	"6660188"	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 15:59
S84	0	semiconductor near2 precursor (oxidized or reduced) inorganic semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:10
S85	0	semiconductor near2 precursor (oxidized or reduced) inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:11
S86	1	semiconductor near4 precursor (oxidized or reduced) inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:11
S87	1	semiconductor near4 precursor inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:11
S88	29	(oxidized or reduced) inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:15
S89	1	precursor (oxidiz\$3 or reduct\$3) inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:23

S90	1	electrolyte(oxidiz\$3 or reduct\$3) inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	SAME	ON	2010/05/20 16:23
S91	468	naito-kazumi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 16:31
S92	276	electrolytic adj capacitor and naito-kazumi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 16:31
S93	16	electrolytic adj capacitor and inorganic adj semiconductor same (energization or energizing or current or potential) and naito-kazumi.in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 16:32
S94	17	electrolytic adj capacitor and inorganic adj semiconductor same (energization or energizing or current or potential)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/20 16:33
S95	5	"576416".ap.	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/05/21 21:59
S96	91	(lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate)and inorganic adj semiconductor and electrolytic adj capacitor	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/05/21 22:06
S97	3	(lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate)same inorganic adj semiconductor and electrolytic adj capacitor and (energization or current or potential)	US-PGPUB; USPAT; USOCR; FPRS	OR	ON	2010/05/21 22:15

S98	3	(lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate)same inorganic adj semiconductor and electrolytic adj capacitor and (energization or current or potential)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:16
S99	1	(lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate)same inorganic adj semiconductor and electrolytic adj capacitor same (energization or current or potential or V)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:24
S100	1	(precursor or lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate) same inorganic adj semiconductor and electrolytic adj capacitor same (energization or current or potential or V)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:24
S101	3	(precursor or lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate) same inorganic adj semiconductor and electrolytic adj capacitor and (energization or current or potential or V)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:25

S102	3	(precursor or lead adj acetate or manganese adj acetate or sodium adj molybdate or sodium adj tungstate) same inorganic adj semiconductor and electrolytic adj capacitor and (energiz \$5 or current or potential or V)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:28
S103	5	"576416".ap.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2010/05/21 22:55

EAST Search History (Interference)

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